TGA2590-CP 6 – 12 GHz 30 W GaN Power Amplifier

Product Description

Qorvo's TGA2590-CP is a wideband MMIC power amplifier fabricated on Qorvo's QGaN25 0.25um GaN on SiC process. The TGA2590-CP operates from 6-12GHz and provides 30W of saturated output power with >22dB of large signal gain and >30% power-added efficiency.

The TGA2590-CP is offered in a 10-lead 15 x 15 mm boltdown package. The package has a pure Cu base, offering superior thermal management.

The TGA2590-CP is fully matched to 50Ω with DC blocking caps at both RF ports allowing for simple system integration. The broadband performance supports both electronic warfare and radar opportunities across defense and commercial markets.

Lead-free and RoHS compliant.

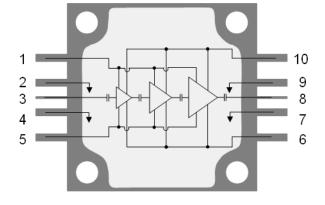


Product Features

- Frequency Range: 6-12 GHz
- P_{OUT}: 45 dBm @ P_{IN} = 23 dBm
- PAE: >30% @ P_{IN} = 23 dBm
- Small Signal Gain: 35 dB
- Bias: V_D = +20 V (CW), I_{DQ} = 2 A, V_G = -2.4 V typical
- Package Dimensions: 15.2 x 15.2 x 3.5 mm
- Package base is pure Cu offering superior thermal management

Performance is typical across frequency. Please reference electrical specification table and data plots for more details

Functional Block Diagram



Applications

- Electronic Warfare
- Commercial and Military Radar

Ordering Information

Part No.	Description
TGA2590-CP	6 – 12 GHz 30 W GaN Power Amplifier
1098063	TGA2590-CP Evaluation Board

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Absolute Maximum Ratings

Parameter	Value / Range
Drain Voltage (V _D)	40 V
Gate Voltage Range (V _G)	-8 to 0 V
Drain Current (I _D)	8 A
Gate Current (I _G)	See plot page 6
Power Dissipation (PDISS), 85°C	135 W
Input Power (P _{IN}), 50Ω, 85°C, CW	30 dBm
Input Power (P_{IN}), 85°C, VSWR 6:1, V _D = 20V, CW	27 dBm
Mounting Temperature	Refer to Assembly Notes, page 9
Storage Temperature	−55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

Parameter	Min	Тур.	Max	Units
Drain Voltage (V _D)	+20		+25	V
Drain Current, (IDQ)		2		Α
Gate Voltage Range (V _G)		-2 to -3		V
Input Power (PIN)	+17		+25	dBm
TBASE Range	-40		+85	°C

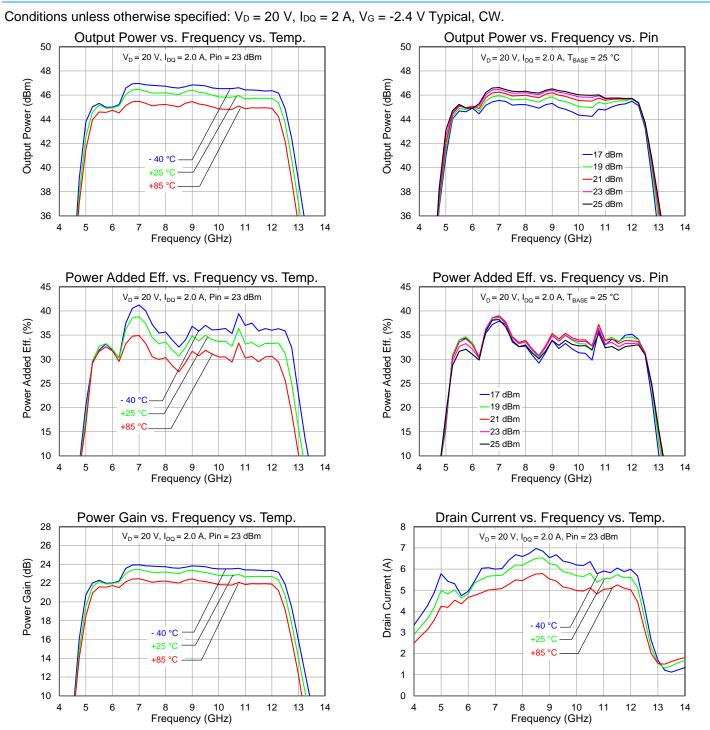
Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Parameter	Min	Тур	Max	Units
Operational Frequency Range	6		12	GHz
Small Signal Gain	-	35	-	dB
Input Return Loss	-	5	-	dB
Output Return Loss	-	5	-	dB
Output Power (@ P _{IN} = 23 dBm)	-	46	-	dBm
Power Added Efficiency (@ P _{IN} = 23 dBm)	-	>30	-	%
Drain Voltage (V _D)	20	-	25	V
Load VSWR	-	-	2.0:1	
Input Power (P _{IN})	17	-	25	dBm
Small Signal Gain Temperature Coefficient		-0.07		dB/°C
Output Power Temperature Coefficient		-0.015		dBm/°C

Test conditions unless otherwise noted: 25 °C, $V_D = +20 V$, $I_{DQ} = 2 A$, $V_G = -2.4 V$ typical, CW.

Typical Performance – Large Signal

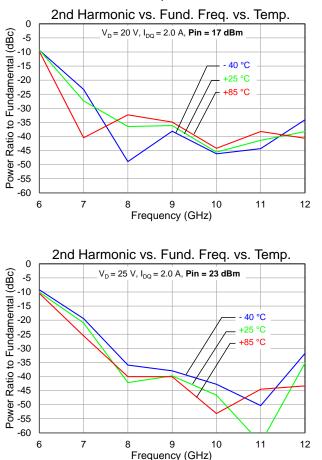


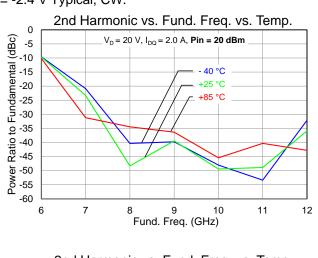
QOCVO

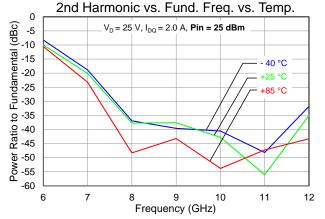
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Typical Performance – Large Signal (Harmonics)

Conditions unless otherwise specified: $V_D = 20 \text{ V}$, $I_{DQ} = 2 \text{ A}$, $V_G = -2.4 \text{ V}$ Typical, CW.





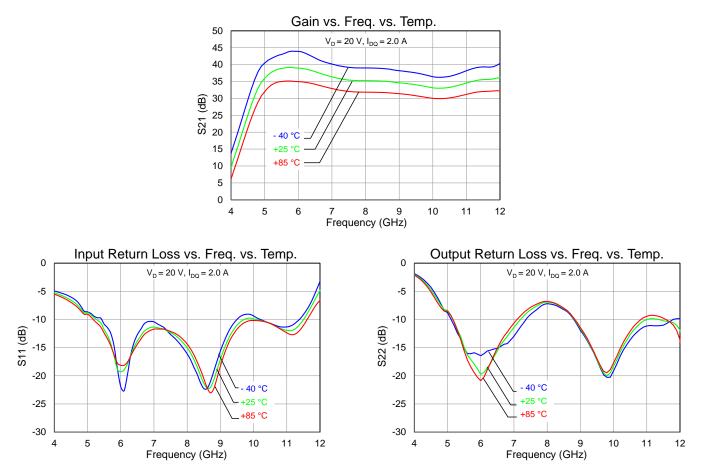


QOCVO.

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Performance Plots – Small Signal (CW)

Conditions unless otherwise specified: V_D = 20 V, I_{DQ} = 2 A, V_G = -2.4 V Typical, CW.



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Thermal and Reliability Information

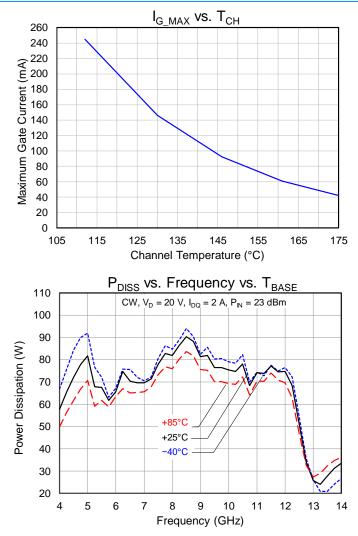
Parameter	Test Conditions	Value	Units
Thermal Resistance (θ_{JC}) ⁽¹⁾	Vb = 20 V, Ibq = 2 A, Freq. = 8.5 GHz	0.81	°C/W
Channel Temperature, T _{CH} (Under RF) ⁽²⁾	$T_{\text{base}} = 85 \text{ °C}, V_D = 20 \text{ V}, I_{D_D\text{rive}} = 5.8 \text{ A},$ PIN = 23 dBm, POUT = 45 dBm, P _{DISS} = 83.8 W	153	°C

Notes:

1. Thermal resistance is referenced to the back of package (85 °C)

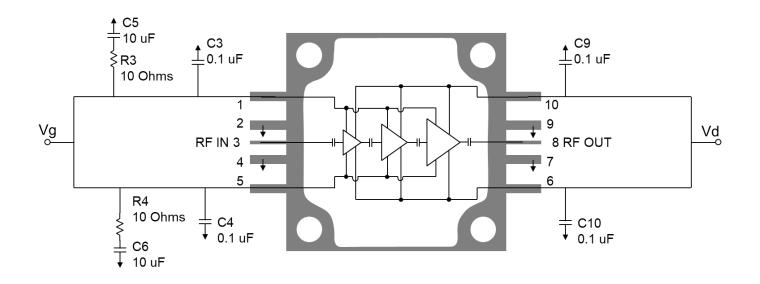
2. Refer to the following document: GaN Device Channel Temperature, Thermal Resistance, and Reliability Estimates

Dissipated Power and Maximum Gate Current



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Applications Information and Pin Layout



Notes:

- 1. V_G must be biased from both sides (Pins 1 and 5)
- 2. V_D must be biased from both sides (Pins 6 and 10)

Bias Up Procedure

- 1. Set I_D limit to 8 A, I_G limit to 200 mA
- 2. Apply -5 V to V_G
- 3. Apply 20 V to $V_{\text{D}};$ ensure I_{DQ} is approx. 0 mA
- 4. Adjust V_G until $I_{DQ} = 2 \text{ A} (V_G \sim -2.4 \text{ V Typ.}).$
- 5. Turn on RF supply

Bias Down Procedure

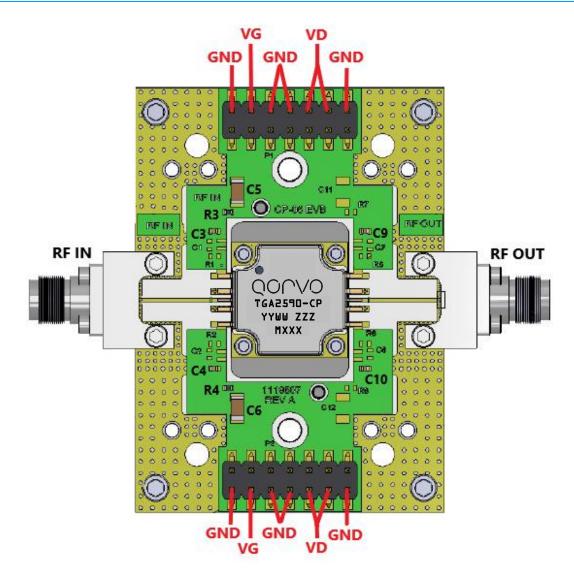
- 1. Turn off RF supply
- 2. Reduce V_G to $-5\,V;$ ensure I_{DQ} is approx. 0 mA
- 3. Set V_D to 0 V
- 4. Turn off V_D supply
- 5. Turn off V_G supply

Pad No.	Symbol	Description
1,5	V _G	Gate Voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
2,4,7,9	GND	Must be grounded on the PCB.
3	RFIN	Input; matched to 50 Ω; DC blocked
6,10	VD	Drain voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
8	RFout	Output; matched to 50 Ω; DC blocked.

Pin Description

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Evaluation Board (EVB) Assembly Drawing



PCB NOTES:

1. PCB is made from Rogers 4003C dielectric, 0.008 inch thick, 0.5 oz. copper both sides.

2. Both Top and Bottom V_D and V_G must be biased.

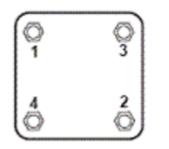
Bill of Materials

Reference Des.	Value	Description	Manuf.	Part Number
C3, C4, C9, C10	0.1 µF	Cap, 0402, 50 V, 10%, X7R	Various	-
C5, C6	10 uF	Cap, 1206, 50 V, 20%, X5R	Various	-
R3, R4	10 Ω	Res, 0402, 5%	Various	-

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Assembly Notes

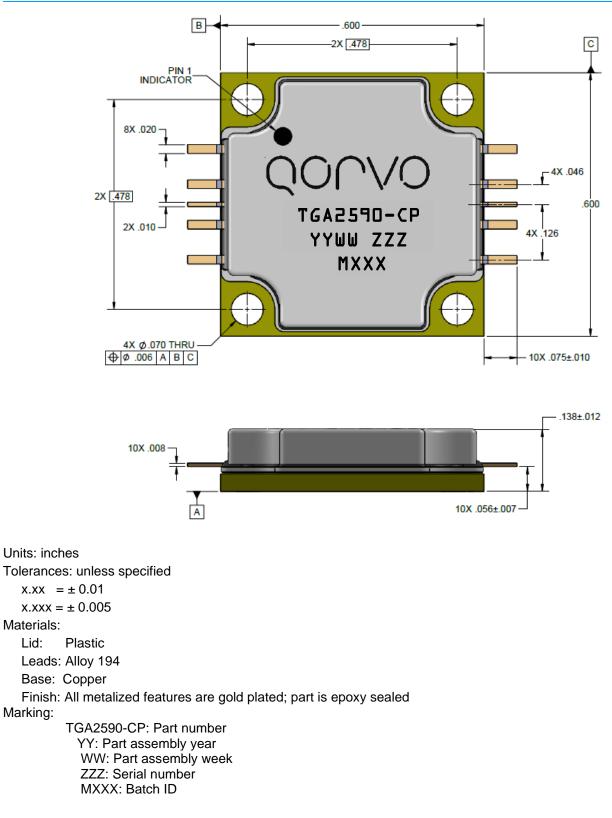
- 1. Carefully clean the PC board and package leads with alcohol. Allow it to dry fully.
- 2. To improve the thermal and RF performance, Qorvo recommends attaching a heat sink to the bottom of the PCB and apply thermal compound (Arctic Silver 5 recommended) or 4 mil indium shim between the heat sink and the package.
- 3. (The following is for <u>information only</u>. There are many variables in a second level assembly that Qorvo does not control, so Qorvo does not recommend an absolute torque value.) Use screws to attach the component to the heat sink. A suggested torque value is 16 in-oz. for a 0-80 screw. Start with screws finger tight, then torque to 8 in-oz., then torque to final value. Use the following tightening pattern:



4. The component leads should be manually soldered. Apply a low residue solder alloy meeting J-STD-001 (ROL0, ROL1 or equivalent) with a liquidus temperature below 220 C to each pin of the TGA2590-CP. The use of low residue/no-clean flux (ROL0, ROL1) is recommended. Adding flux during hand soldering of the component leads with localized spot cleaning is acceptable. Soldering irons meeting the requirements of J-STD-001, Appendix A are acceptable. The packaged part should not be subjected to conventional SMT automated solder reflow processes.

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Mechanical Information



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Handling Precautions

Parameter	Rating	Standard		
ESD-Human Body Model (HBM)	Class 1B	JEDEC Standard JESD22 A114		Caution!
ESD-Charge Device Model (CDM)	Class C3	JEDEC Standard JESD22-C101F	12	ESD-Sensitive Device
MSL-Moisture Sensitivity Level	N/A			

Solderability

The component leads should be manually soldered, and the package cannot be subjected to conventional reflow processes. The use of no-clean solder to avoid washing after soldering is recommended.

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU. This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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